

(Dielectric)

# "Soft" Parallel Plate Capacitor

- Sensor capacitance changes w/ pressure & stretch
- Actuator thickness decreases (area increases) under applied electrostatic pressure ("Maxwell Stress")
- Generator/Transducer elastic deformation changes electrostatic potential of surface charge

# Implementation

- Circular Membrane prestretch and bond to a rigid ring
- Flexural Structure prestretch capacitor and bond to a flexible substrate
- **Stacked Capacitor** no prestretch; requires IPN treatment to enhance dielectric breakdown strength
- **Balloon** thin-walled spherical capacitor; inflate with air
- **Spring-roll** thin-walled cylindrical capacitor; prestretch and rolled around a helical spring

## **Parallel-Plate Capacitor**



units:  $F = "Farad" = N-m/V^2$ Electric permittivity:  $\varepsilon = \varepsilon_r \varepsilon_0$  $\varepsilon_0 = 8.85 \times 10^{-12} \text{ F/m} = \text{vacuum permittivity}$  $\varepsilon_r = \text{relative permittivity}$  ("dielectric constant") e.g. air ~ 1; rubber ~ 2-5; silicon ~ 11; water ~ 100; PZT ~ 1000  $\frac{\text{Analogy}}{\Phi = \text{C}^{-1}\text{q} \sim \text{F} = \text{kx}}$  $\Phi \sim \text{F, C} \sim \text{k}^{-1}, \text{q} \sim \text{x}$ 

Electric displacement: D = q/AElectric Field:  $E = \Phi/t$ Maxwell's equation:  $D = \varepsilon E$ 

### **Capacitive Sensing**



Uniaxial strain:  $\lambda_1 = \lambda, \lambda_2 = \lambda_3 = \lambda^{-1/2} \Longrightarrow C/C_0 = \lambda$ 

Biaxial strain:  $\lambda_1 = \lambda_2 = \lambda, \lambda_3 = \lambda^{-2} \Longrightarrow C/C_0 = \lambda^4$ 

Pressure/squeezing:  $\lambda_3 = \lambda$ ,  $\lambda_1 = \lambda_2 = \lambda^{-1/2} \Rightarrow C/C_0 = \lambda^{-2}$ 

# **Maxwell Stress**





Equibiaxial loading:  $\lambda_1=\lambda_2=\lambda^{-2}$  ,  $\lambda_3=\lambda$ 

Prescribed surface charge: q

Voltage:  $\Phi = q/C$ 

Maxwell Stress:  $\sigma = qE/A$ 

# **Circular Membrane**

High-speed electrically actuated elastomers with strain greater than 100% Ron Pelrine, Roy Konbluh, Qibing Pei, Jose Joseph, *Science* vol. 287 (2000)

**1739 citations** (as of 2/17/16)



Voltage limited by *electromechanical instability* when  $\Phi = \Phi_{cr} := t_0 \sqrt{\frac{\mu}{\epsilon}}$ 



Typical values:

- $t_0 \sim 10^{-4} \, m$
- $\mu \sim 10^5 \, Pa$

 $\Phi_{\rm cr} = t_0 \sqrt{\frac{\mu}{\epsilon}} \sim 10^{-4} \sqrt{\frac{10^5}{10^{-11}}} \sim 10^4 \,\rm V$ 

•  $\epsilon \sim 10^{-11} \, F/m$ 

# **Electromechanical Instability (Pull-In)**

#### Very high dielectric strength for dielectric elastomer actuators in liquid dielectric immersion

T-G La and G-K Lau APL 102 192905 (2013)



# **Electromechanical Instability (Creasing)**

# **Electro-creasing instability in deformed polymers:** experiment and theory

Q. Wang, M. Tahir, L. Zhang, X. Zhao Soft Matter 7 6583 (2011)







The voltage is also limited by *electrical breakdown*:

- Internal electric field is so large that bound charge carriers get energized and mobilized
- The charges (electrons or ions) crash into neighbors and form a cascade of interactions
- Excited charges carry current through the dielectric and cause an electrical discharge (much like lightening in air)
- Dielectric momentarily acts like a conductor can lead to permanent damage
- To prevent breakdown, E must remain less than the breakdown strength  $E_b$

$$\mathbf{E} = \frac{\Phi}{\lambda t_0} = \frac{\hat{\Phi}}{\lambda} \sqrt{\frac{\mu}{\epsilon}} < \mathbf{E}_{b} \Longrightarrow \boxed{\lambda > \frac{\hat{\Phi}}{\mathbf{E}_{b}} \sqrt{\frac{\mu}{\epsilon}}}$$



Typical values:

- $\mu \sim 10^5 \, Pa$
- $\bullet \quad \epsilon \sim 10^{\text{--}11}\,\text{F/m}$

• 
$$E_b \sim 10^7 - 10^8 \, MV/m$$

$$\lambda > \frac{\hat{\Phi}}{E_{b}} \sqrt{\frac{\mu}{\epsilon}} \sim \left\{ \frac{1}{10^{8}} \sqrt{\frac{10^{5}}{10^{-11}}} \right\} \hat{\Phi} \sim \hat{\Phi}$$

# **Electrical Breakdown in Dielectrics**

#### MANCHESTER 1824

The University of Manchester

# Electrical breakdown through an electrical tree

R. Schurch, S. M. Rowland, R. S. Bradley and J. P. Withers

#### "A Novel Approach for Imaging of Electrical Trees"

IEEE Conference on Electrical Insulation and Dielectric Phenomena, Montreal - 2012

R. Schurch, S. M. Rowland and J. P. Withers

#### "Techniques for Electrical Tree Imaging"

IEEE Conference on Imaging Systems and Techniques, Manchester - 2012



Polymer film stretched on a rigid frame Top electrode	Bottom electrode		Material	Prestrain (x,y) (%)	Actuated relative thickness strain (%)	Actuated relative area strain (%)	Field strength (MV/m)
Rigid	∠ L'→x					ılar strain	$\frown$
irame voitage	OIT	Voltage on	HS3 silicone	(68,68)	48	93	110
				(14,14)	41	69	72
			CF19-2186 silicone	(45,45)	39	64	350
				(15,15)	25	33	160
			VHB 4910 acrylic	(300,300)	61	158	412
Voltage	off	Voltage on		(15,15)	29	40	55

High-speed electrically actuated elastomers with strain greater than 100% Ron Pelrine, Roy Konbluh, Qibing Pei, Jose Joseph, *Science* vol. 287 (2000)

# **Energy Method**

When charge is the free variable, use the "internal electrical energy":  $u = \frac{1}{2} \underline{D} \cdot \underline{E}$ 

The total electrical energy is calculated by integrating over the volume in the <u>current</u> placement:  $\Gamma = \int_{B} \left\{ \frac{1}{2} \underline{D} \cdot \underline{E} \right\} dV$ 

For a parallel-plate capacitor,  $\underline{E} = (F/h)\underline{e}_3$  and  $\underline{D} = (q/A)\underline{e}_3$ 

$$\Gamma = \int_{B} \left\{ \frac{1}{2} \underline{D} \cdot \underline{E} \right\} dV = \frac{1}{2} \left( \frac{q}{A} \right) \left( \frac{\Phi}{h} \right) (Ah) = \frac{1}{2} q\Phi$$
  
Noting that F = q/C,  $\Gamma = \frac{q^2}{2C}$ 

Referring to the "spring analogy"  $F \sim F$ ,  $u \sim q$ , and  $k \sim C^{-1}$ , the internal electrical energy has the same form as the elastic spring energy ku<sup>2</sup>/2.

As with spring energy, an alternative way to derive G for a parallel plate capacitor is by integrating F for charge increasing from 0 to q:  $\Gamma = \int_0^q \frac{\hat{q}}{C} d\hat{q}$ 

### Example

Consider the same Ogden solid as before:

W = 
$$\frac{\mu}{4} \left( \lambda_1^4 + \lambda_2^4 + \lambda_3^4 - 3 \right) = \frac{\mu}{4} \left( \frac{2}{\lambda^2} + \lambda^4 - 3 \right)$$

The total potential energy is  $\Pi = WV_0 + \Gamma$ 

where 
$$\Gamma = \frac{q^2}{2C} = \frac{hq^2}{2\epsilon A} = \frac{\lambda^2 h_0 q^2}{2\epsilon A_0}$$

$$\Rightarrow \Pi = \frac{\mu}{4} \left( \frac{2}{\lambda^2} + \lambda^4 - 3 \right) A_0 h_0 + \frac{\lambda^2 t_0 q^2}{2\epsilon A_0}$$

If q is prescribed as a fixed value, then  $\Pi$  is only minimized w.r.t.  $\lambda$ :

$$\frac{d\Pi}{d\lambda} = \mu \left(\lambda^3 - \frac{1}{\lambda^3}\right) A_0 t_0 + \frac{\lambda t_0 q^2}{\varepsilon A_0} \equiv 0$$

... must solve numerically for  $\lambda$ .

Now suppose that  $\Phi$  is prescribed/fixed and q is unknown. This is analogous to stretching a spring with a prescribed force F. In this case, the potential becomes

$$\Pi = WV_0 + \Gamma - q\Phi.$$

The proof is similar to before. Applying a voltage  $\Phi$  to the capacitor results in a charge q\* = C $\Phi$  at electrostatic equilibrium. Now suppose that the capacitor is loaded with additional charge  $\delta q$ . The electrostatic work required to elevate  $\delta q$  to a voltage  $\Phi$  must be balanced by the change in internal electrical energy:

$$\delta \Gamma = \int_{q^*}^{q^* + \delta q} \Phi \, dq = \Phi \delta q \Longrightarrow \delta \big( \Gamma - q \Phi \big) = 0$$

This implies that for variations in q,  $\Gamma$  must be replaced by  $\hat{\Gamma} = \Gamma - q\Phi$ .

Now,  $\Pi$  must be minimized w.r.t.  $\lambda$  and q:

$$\Pi = \frac{\mu}{4} \left( \frac{2}{\lambda^2} + \lambda^4 - 3 \right) A_0 h_0 + \frac{\lambda^2 t_0 q^2}{2\epsilon A_0} - q \Phi$$

$$\frac{d\Pi}{dq} = \frac{\lambda^2 t_0 q}{\epsilon A_0} - \Phi \equiv 0 \Longrightarrow q = \frac{\epsilon A_0}{\lambda^2 t_0} \Phi$$

$$\frac{d\Pi}{d\lambda} = \mu \left( \lambda^3 - \frac{1}{\lambda^3} \right) A_0 t_0 + \frac{\lambda t_0 q^2}{\epsilon A_0} \equiv 0 \qquad \therefore \lambda = \left\{ 1 - \frac{\epsilon \Phi^2}{\mu t_0^2} \right\}^{1/6} \checkmark$$

For cases when  $\Phi$  is prescribed, a shortcut is to use the electrical enthalpy instead of internal energy. This is associated with a change of variables for  $\Pi$ :

$$\Pi = \Pi (\lambda, q) \rightarrow \tilde{\Pi} = \tilde{\Pi} (\lambda, \Phi).$$

Recall  $\Pi = WV_0 + \Gamma - q\Phi$ 

$$= WV_0 - q\Phi + \int_0^q \Phi d\hat{q}$$

Performing an integration by parts ("Legendre Transformation")

$$\begin{split} \tilde{\Pi} &= WV_0 - q\Phi + q\Phi - \int_0^{\Phi} q \, d\hat{\Phi} \\ &= WV_0 - \frac{1}{2}C\Phi^2 \\ \text{``Electrical Enthalpy''} \\ \Pi &= \frac{\mu}{4} \left(\frac{2}{\lambda^2} + \lambda^4 - 3\right) A_0 t_0 - \frac{\varepsilon A_0 \Phi^2}{2\lambda^2 t_0} \\ &\frac{d\Pi}{d\lambda} = \mu \left(\lambda^3 - \frac{1}{\lambda^3}\right) A_0 t_0 + \frac{\varepsilon A_0 \Phi^2}{\lambda^3 t_0} \equiv 0 \qquad \therefore \lambda = \left\{1 - \frac{\varepsilon \Phi^2}{\mu t_0^2}\right\}^{1/6} \end{split}$$

# **DEA Generator**



# **DEA Generator**

Harvest electrical energy from changes in fluid pressure

- Balloon
- Energy harvesting shoe
- Ocean waves



i Compressed Air In

ii Voltage Applied

# **Balloon Generator**



Kaltseis, Suo, Bauer, et al. APL (2011)



### **DEA Generator**



to mimetics laboratory

#### Soft Power Generation

Iain Anderson (Univ. Auckland)

0.8 J per step Avg. Power ~ 1 Watt Specific Energy: 0.3J/g **33% conversion** 

# **PolyWEC**

Polymeric Wave Energy Converter

- EU funded project (2012-2016; >2mil. euros)
- Lead: Marco Fontana (SSSA) ۲
- Partner: Univ. of Edinburgh ۲





DEG